EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	53	(349/45).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/04/27 15:30
L2	7061	(438/48,128,149,151,157,283). CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/04/27 15:30
L3	832	2 and (@ad<"20030110") and (glass with substrate) and ((thin adj fiml adj transistor) or (tft))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/04/27 15:37
L4	940	2 and (@ad<"20030110") and (glass with substrate) and ((thin adj film adj transistor) or (tft))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/04/27 15:54
L5	0	("(SiNwith(thermaladjconductivity))").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/04/27 15:54
L6	0	("(SiNwith(thermaladjconductivity))").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/04/27 15:55
L7	0	("(SiNwith(thermaladjconductivity))").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/04/27 15:55
L8	181	(SiN with (thermal adj conductivity))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/04/27 16:07

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L9	2256	(SiN with (flexible))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/04/27 16:07
L10	29	(SiN with (flexible)) and (thin adj film adj transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/04/27 16:10
L11	81	(SiN with (flexible)) and (tft) not 10	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/04/27 16:12
L12	78	(SiN with (flexible)) and (semiconductor) not (10 and 11)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/04/27 16:16
L13	2	("20030151049").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/04/27 16:16